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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR 2SK3740

# SWITCHING N-CHANNEL POWER MOS FET

# **DESCRIPTION**

The 2SK3740 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, designed for high voltage applications such as lamp drive, DC/DC converter, and actuator driver.

# **FEATURES**

- Gate voltage rating: ±30 V
- Low on-state resistance

 $R_{DS(on)}$  = 160 m $\Omega$  MAX. (Vgs = 10 V, ID = 10 A)

• Low gate charge

 $Q_G = 47 \text{ nC TYP.}$  (VDD = 200 V, VGS = 10 V, ID = 20 A)

• Surface mount package available

# ORDERING INFORMATION

| PART NUMBER | PACKAGE          |
|-------------|------------------|
| 2SK3740-ZK  | TO-263 (MP-25ZK) |



# ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

| Drain to Source Voltage (VGS = 0 V) | VDSS            | 250         | V  |
|-------------------------------------|-----------------|-------------|----|
| Gate to Source Voltage (VDS = 0 V)  | Vgss            | ±30         | V  |
| Drain Current (DC) (Tc = 25°C)      | ID(DC)          | ±20         | Α  |
| Drain Current (pulse) Note1         | ID(pulse)       | ±60         | Α  |
| Total Power Dissipation             | P <sub>T1</sub> | 1.5         | W  |
| Total Power Dissipation (Tc = 25°C) | P <sub>T2</sub> | 100         | W  |
| Channel Temperature                 | Tch             | 150         | °C |
| Storage Temperature                 | Tstg            | -55 to +150 | °C |
| Single Avalanche Current Note2      | las             | 20          | Α  |
| Single Avalanche Energy Note2       | Eas             | 40          | mJ |

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

**2.** Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = 125 V, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V, L = 100  $\mu$ H

# THERMAL RESISTANCE

| Channel to Case Thermal Resistance    | Rth(ch-C) | 1.25 | °C/W |
|---------------------------------------|-----------|------|------|
| Channel to Ambient Thermal Resistance | Rth(ch-A) | 83.3 | °C/W |

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**ELECTRICAL CHARACTERISTICS (TA = 25°C)** 

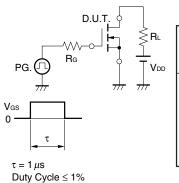
|  | •                    | ,   |      |      |      |      |
|--|----------------------|---|------|------|------|------|
| CHARACTERISTICS                          | SYMBOL               | TEST CONDITIONS                                 | MIN. | TYP. | MAX. | UNIT |
| Zero Gate Voltage Drain Current          | IDSS                 | V <sub>DS</sub> = 250 V, V <sub>GS</sub> = 0 V  |      |      | 10   | μΑ   |
| Gate Leakage Current                     | Igss                 | V <sub>GS</sub> = ±30 V, V <sub>DS</sub> = 0 V  |      |      | ±10  | μΑ   |
| Gate Cut-off Voltage                     | V <sub>GS(off)</sub> | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 mA | 2.5  | 3.5  | 4.5  | V    |
| Forward Transfer Admittance Note         | y <sub>fs</sub>      | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 10 A   | 7.0  | 15   |      | S    |
| Drain to Source On-state Resistance Note | R <sub>DS(on)</sub>  | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A   |      | 0.12 | 0.16 | Ω    |
| Input Capacitance                        | Ciss                 | V <sub>DS</sub> = 10 V                          |      | 1720 |      | pF   |
| Output Capacitance                       | Coss                 | V <sub>GS</sub> = 0 V                           |      | 330  |      | pF   |
| Reverse Transfer Capacitance             | Crss                 | f = 1.0 MHz                                     |      | 170  |      | pF   |
| Turn-on Delay Time                       | t <sub>d(on)</sub>   | V <sub>DD</sub> = 125 V, I <sub>D</sub> = 10 A  |      | 17   |      | ns   |
| Rise Time                                | tr                   | V <sub>GS</sub> = 10 V                          |      | 17   |      | ns   |
| Turn-off Delay Time                      | <b>t</b> d(off)      | R <sub>G</sub> = 0 Ω                            | ·C   | 49   |      | ns   |
| Fall Time                                | tr                   |   |      | 9    |      | ns   |
| Total Gate Charge                        | Q <sub>G</sub>       | V <sub>DD</sub> = 200 V                         | 6    | 47   |      | nC   |
| Gate to Source Charge                    | Qgs                  | V <sub>GS</sub> = 10 V                          |      | 7    |      | nC   |
| Gate to Drain Charge                     | Q <sub>GD</sub>      | I <sub>D</sub> = 20 A                           |      | 25   |      | nC   |
| Body Diode Forward Voltage Note          | V <sub>F(S-D)</sub>  | IF = 20 A, V <sub>GS</sub> = 0 V                |      | 0.91 |      | V    |
| Reverse Recovery Time                    | trr                  | IF = 20 A, VGS = 0 V                            |      | 210  |      | ns   |
| Reverse Recovery Charge                  | Qrr                  | di/dt = 100 A/μs                                |      | 1.4  |      | μC   |

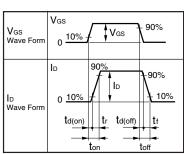
Note Pulsed

# **TEST CIRCUIT 1 AVALANCHE CAPABILITY**

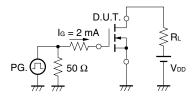
# $V_{GS} = 20 \rightarrow 0 \text{ V}$ $V_{DD}$ $V_{DD}$ $V_{DD}$ $V_{DD}$ $V_{DD}$ $V_{DD}$ $V_{DD}$ $V_{DS}$ $V_{DS}$ $V_{DS}$ $V_{DS}$ $V_{DS}$ $V_{DS}$ $V_{DS}$ $V_{DS}$ $V_{DS}$

# TEST CIRCUIT 2 SWITCHING TIME

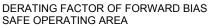


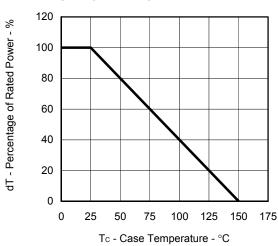


# **TEST CIRCUIT 3 GATE CHARGE**

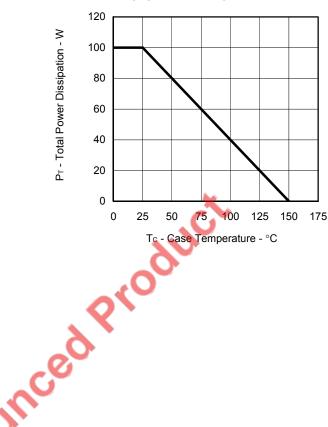


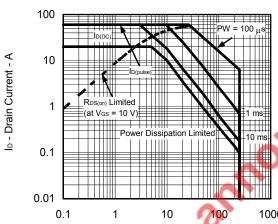
# TYPICAL CHARACTERISTICS (TA = 25°C)



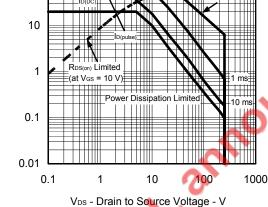


# TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

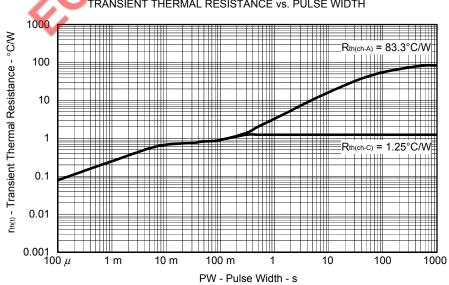




FORWARD BIAS SAFE OPERATING AREA

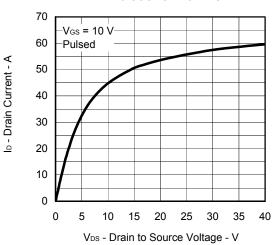


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

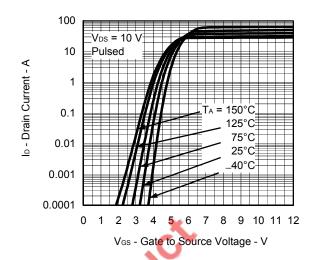


3

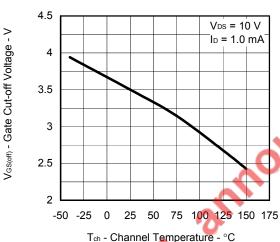
# DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



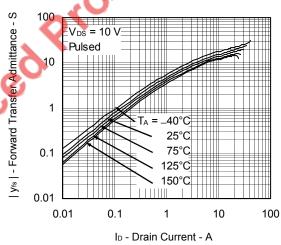
# FORWARD TRANSFER CHARACTERISTICS



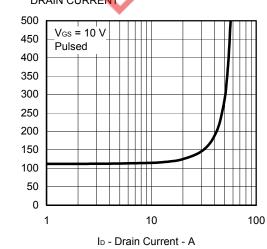
# GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



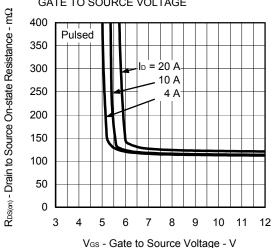
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

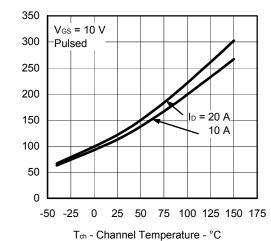


RDS(m) - Drain to Source On-state Resistance - m\Omega

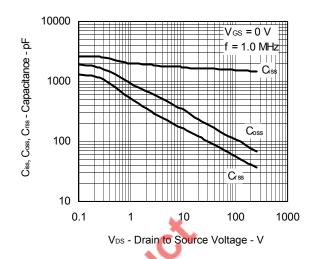
**NEC** 

RDS(on) - Drain to Source On-state Resistance - m\Omega

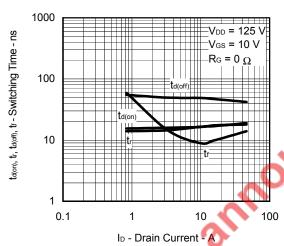
# DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



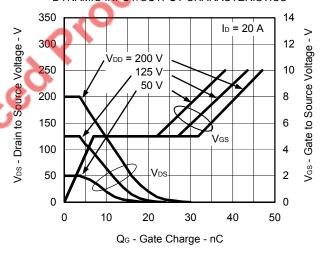
# CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



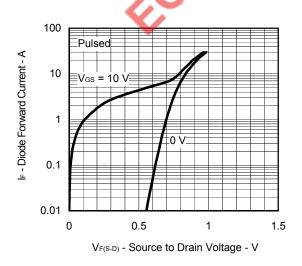
# SWITCHING CHARACTERISTICS



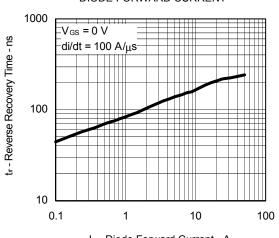
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



# SOURCE TO DRAIN DIODE FORWARD VOLTAGE

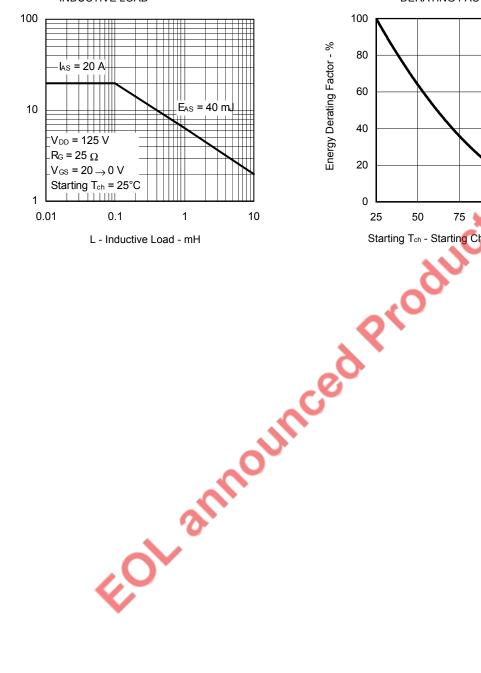


# REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

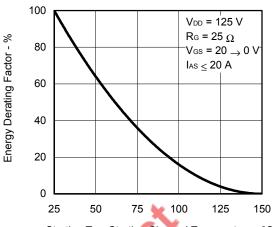


IAS - Single Avalanche Current - A

# SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



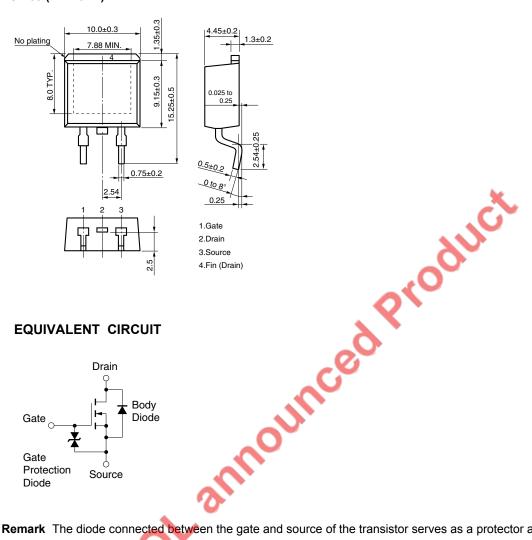
# SINGLE AVALANCHE ENERGY **DERATING FACTOR**



Starting  $\mathsf{T}_\mathsf{ch}$  - Starting Channel Temperature - °C

# PACKAGE DRAWING (Unit: mm)

# TO-263 (MP-25ZK)



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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